

# CSD23382F4 12 V P-Channel FemtoFET™ MOSFET

## 1 Features

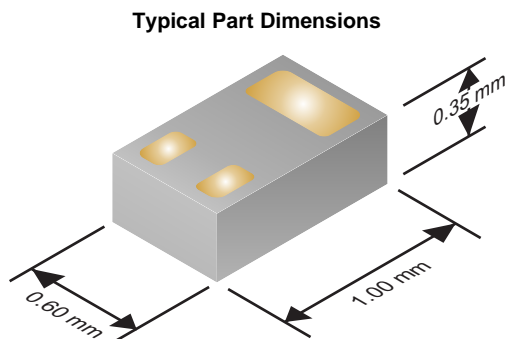
- Low On-Resistance
- Ultra-Low  $Q_g$  and  $Q_{gd}$
- Ultra-Small Footprint (0402 Case Size)
  - 1.0 mm × 0.6 mm
- Low Profile
  - 0.35 mm Max Height
- Integrated ESD Protection Diode
  - Rated >2 kV HBM
  - Rated >2 kV CDM
- Pb Terminal Plating
- Halogen Free
- RoHS Compliant

## 2 Applications

- Optimized for Load Switch Applications
- Optimized for General Purpose Switching Applications
- Battery Applications
- Handheld and Mobile Applications

## 3 Description

This 66 m $\Omega$ , 12 V P-channel FemtoFET™ MOSFET is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.



## Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
$V_{DS}$	Drain-to-Source Voltage	-12		V
$Q_g$	Gate Charge Total (-4.5 V)	1.04		nC
$Q_{gd}$	Gate Charge Gate-to-Drain	0.15		nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = -1.8\text{ V}$	149	m $\Omega$
		$V_{GS} = -2.5\text{ V}$	90	
		$V_{GS} = -4.5\text{ V}$	66	
$V_{GS(th)}$	Threshold Voltage	-0.8		V

## Ordering Information<sup>(1)</sup>

Device	Qty	Media	Package	Ship
CSD23382F4	3000	7-Inch Reel	Femto (0402) 1.0 mm × 0.6 mm Land Grid Array (LGA)	Tape and Reel
CSD23382F4T	250	7-Inch Reel		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

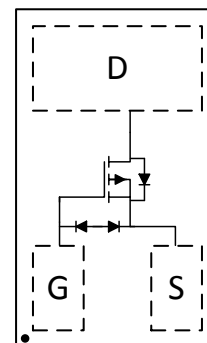
## Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
$V_{DS}$	Drain-to-Source Voltage	-12	V
$V_{GS}$	Gate-to-Source Voltage	$\pm 8$	V
$I_D$	Continuous Drain Current <sup>(1)</sup>	-3.5	A
$I_{DM}$	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ <sup>(2)</sup>	-22	A
$I_G$	Continuous Gate Clamp Current	-35	mA
	Pulsed Gate Clamp Current <sup>(2)</sup>	-350	
$P_D$	Power Dissipation <sup>(1)</sup>	500	mW
$V_{(ESD)}$	Human Body Model (HBM)	2	kV
	Charged Device Model (CDM)	2	kV
$T_J$ , $T_{sig}$	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$

(1) Typical  $R_{\theta JA} = 85^\circ\text{C/W}$  on 1 inch<sup>2</sup> (6.45 cm<sup>2</sup>), 2 oz. (0.071 mm thick) Cu pad on a 0.06 inch (1.52 mm) thick FR4 PCB.

(2) Pulse duration  $\leq 100\ \mu\text{s}$ , duty cycle  $\leq 1\%$

## Top View



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

### Changes from Revision B (July 2014) to Revision C Page

- Corrected timing  $V_{DS}$  to read  $-6\text{ V}$  ..... **3**

### Changes from Revision A (June 2014) to Revision B Page

- Corrected capacitance units to read pF in [Figure 5](#) ..... **5**

### Changes from Original (May 2014) to Revision A Page

- Changed device status to production ..... **1**

## 5 Specifications

### 5.1 Electrical Characteristics

(T<sub>A</sub> = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>STATIC CHARACTERISTICS</b>						
B <sub>V</sub> DSS	Drain-to-Source Voltage	V <sub>GS</sub> = 0 V, I <sub>DS</sub> = -250 μA	-12			V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = -9.6 V			-1	μA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = -8 V			-10	μA
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>DS</sub> = 250 μA	-0.5	-0.8	-1.1	V
R <sub>DS(on)</sub>	Drain-to-Source On-Resistance	V <sub>GS</sub> = -1.8 V, I <sub>DS</sub> = -0.1 A		149	199	mΩ
		V <sub>GS</sub> = -2.5 V, I <sub>DS</sub> = -0.5 A		90	105	mΩ
		V <sub>GS</sub> = -4.5 V, I <sub>DS</sub> = -0.5 A		66	76	mΩ
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = -10 V, I <sub>DS</sub> = -0.5 A		3.4		S
<b>DYNAMIC CHARACTERISTICS</b>						
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = -6 V, f = 1 MHz		180	235	pF
C <sub>oss</sub>	Output Capacitance			118	154	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			12.8	16.6	pF
R <sub>G</sub>	Series Gate Resistance			350		Ω
Q <sub>g</sub>	Gate Charge Total (-4.5 V)	V <sub>DS</sub> = -6 V, I <sub>DS</sub> = -0.5 A		1.04	1.35	nC
Q <sub>gd</sub>	Gate Charge Gate-to-Drain			0.15		nC
Q <sub>gs</sub>	Gate Charge Gate-to-Source			0.50		nC
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>			0.18		nC
Q <sub>oss</sub>	Output Charge	V <sub>DS</sub> = -6 V, V <sub>GS</sub> = 0 V		1.08		nC
t <sub>d(on)</sub>	Turn On Delay Time	V <sub>DS</sub> = -6 V, V <sub>GS</sub> = -4.5 V, I <sub>DS</sub> = -0.5 A, R <sub>G</sub> = 2 Ω		28		ns
t <sub>r</sub>	Rise Time			25		ns
t <sub>d(off)</sub>	Turn Off Delay Time			66		ns
t <sub>f</sub>	Fall Time			41		ns
<b>DIODE CHARACTERISTICS</b>						
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = -0.5 A, V <sub>GS</sub> = 0 V		-0.75	-1	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DS</sub> = -6 V, I <sub>F</sub> = -0.5 A, di/dt = 200 A/μs		1.8		nC
t <sub>rr</sub>	Reverse Recovery Time			8.4		ns

### 5.2 Thermal Information

(T<sub>A</sub> = 25°C unless otherwise stated)

THERMAL METRIC		TYP	UNIT
R <sub>θJA</sub>	Junction-to-Ambient Thermal Resistance <sup>(1)</sup>	85	°C/W
	Junction-to-Ambient Thermal Resistance <sup>(2)</sup>	245	

(1) Device mounted on FR4 material with 1 inch<sup>2</sup> (6.45 cm<sup>2</sup>), 2 oz. (0.071 mm thick) Cu.

(2) Device mounted on FR4 material with minimum Cu mounting area.

### 5.3 Typical MOSFET Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

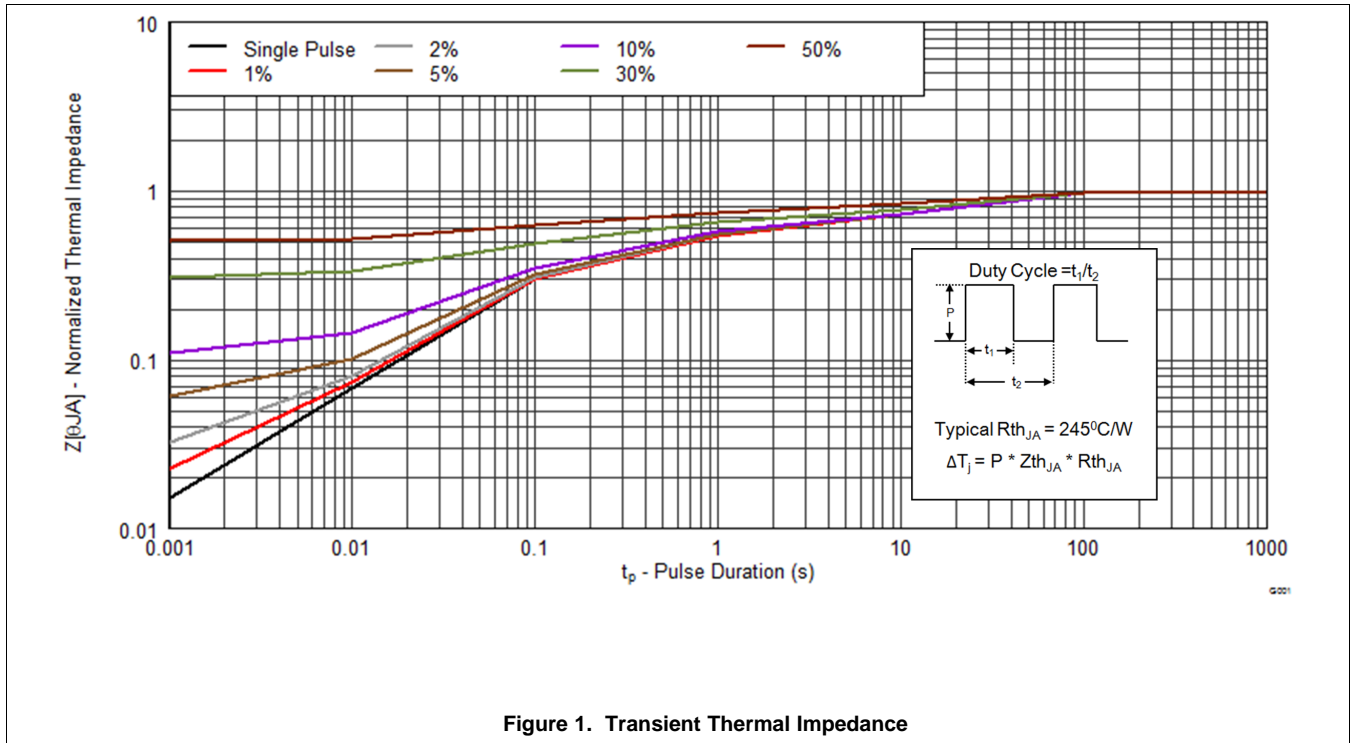


Figure 1. Transient Thermal Impedance

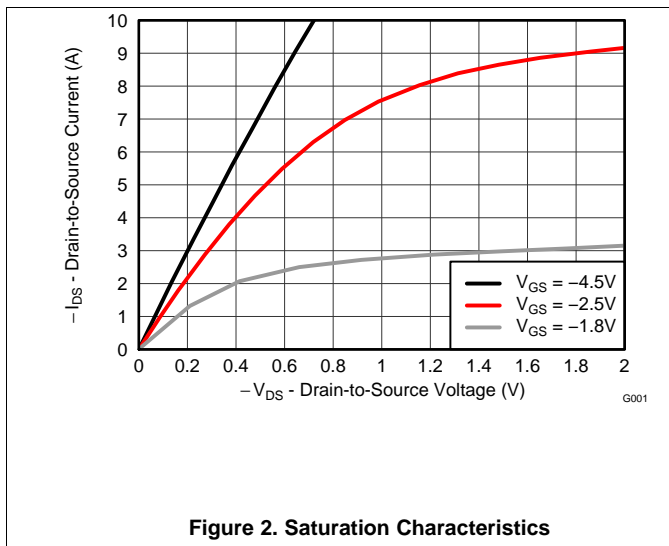


Figure 2. Saturation Characteristics

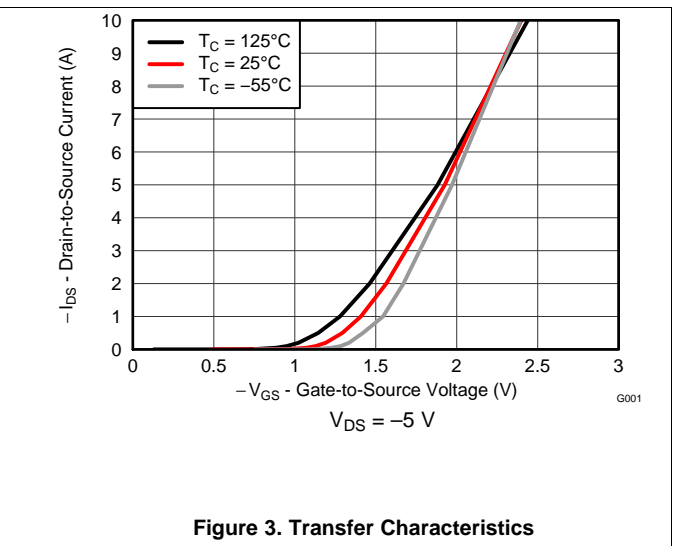


Figure 3. Transfer Characteristics

Typical MOSFET Characteristics (continued)

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

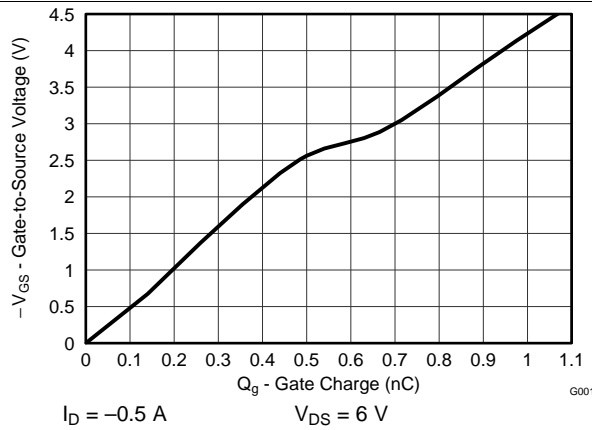


Figure 4. Gate Charge

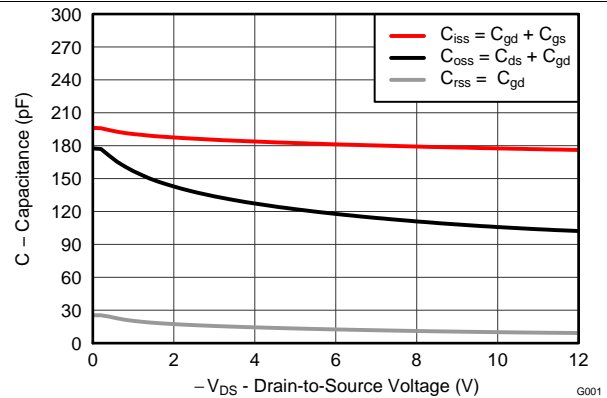


Figure 5. Capacitance

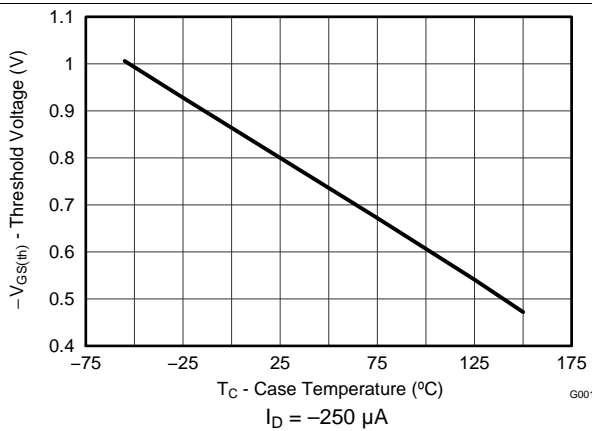


Figure 6. Threshold Voltage vs Temperature

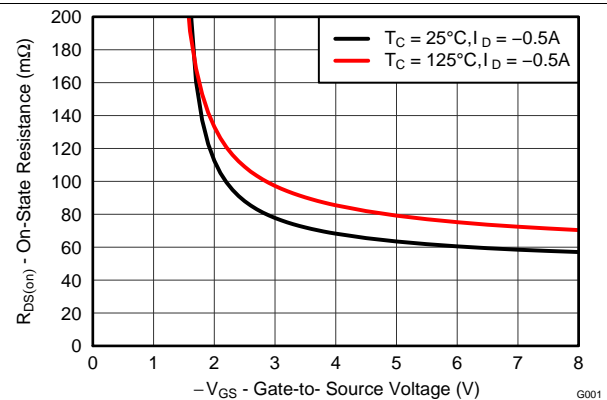


Figure 7. On-State Resistance vs Gate-to-Source Voltage

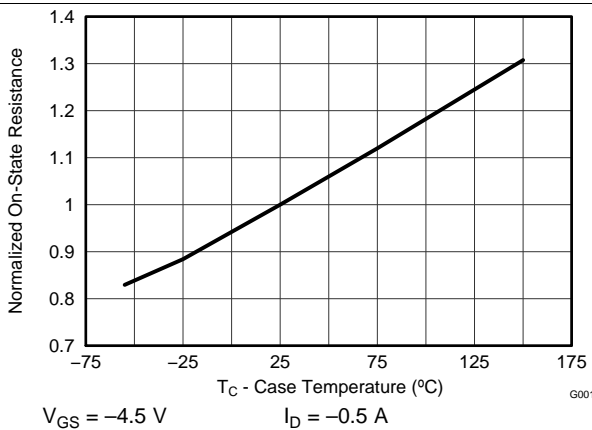


Figure 8. Normalized On-State Resistance vs Temperature

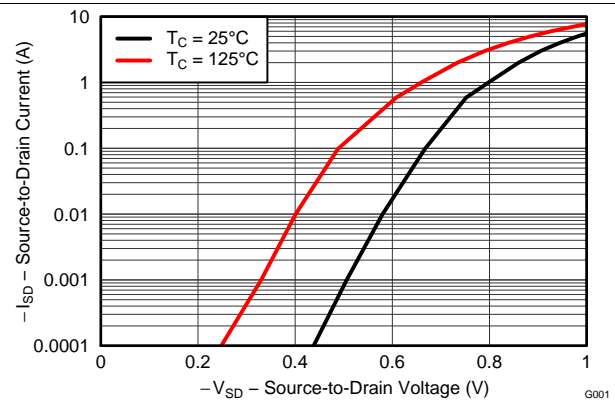
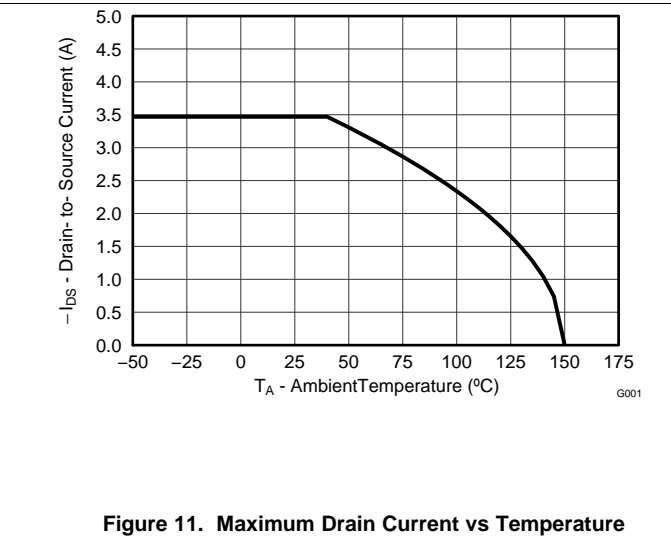
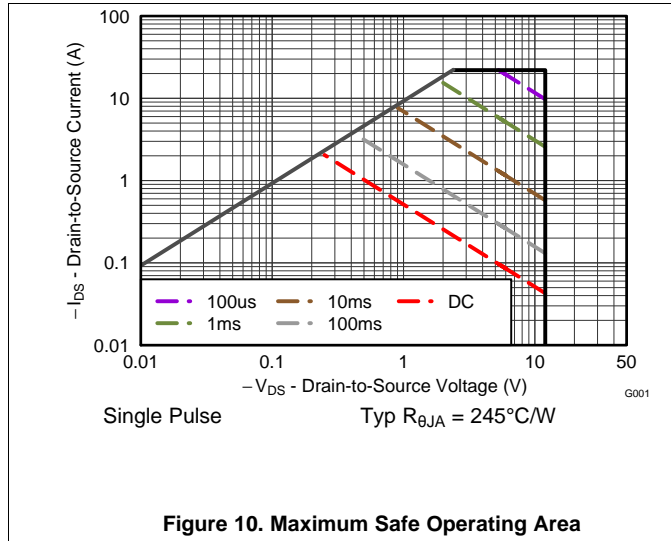


Figure 9. Typical Diode Forward Voltage

**Typical MOSFET Characteristics (continued)**

( $T_A = 25^\circ\text{C}$  unless otherwise stated)



## 6 Device and Documentation Support

### 6.1 Trademarks

FemtoFET is a trademark of Texas Instruments.

### 6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 6.3 Glossary

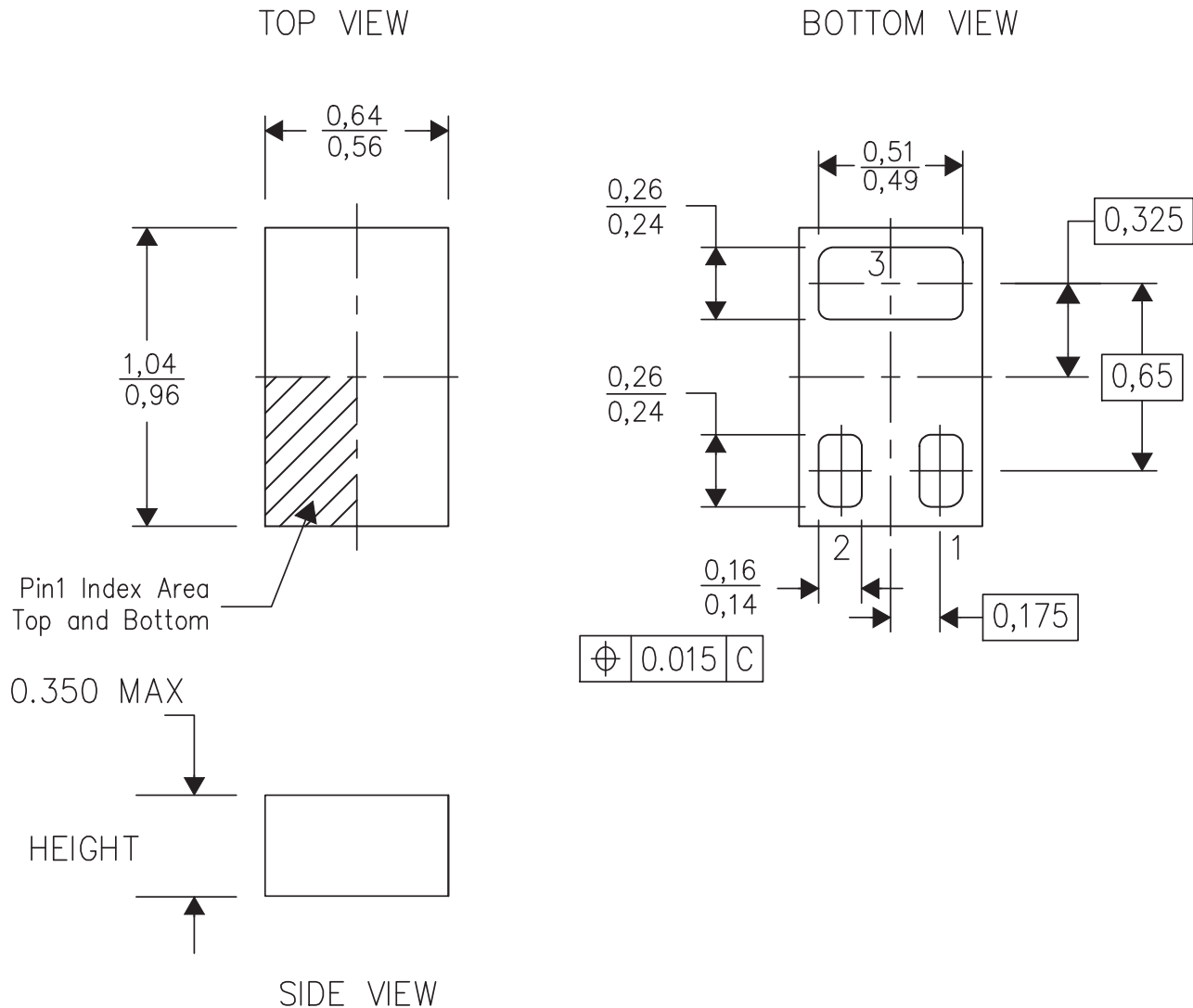
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 7 Mechanical, Packaging, and Orderable Information

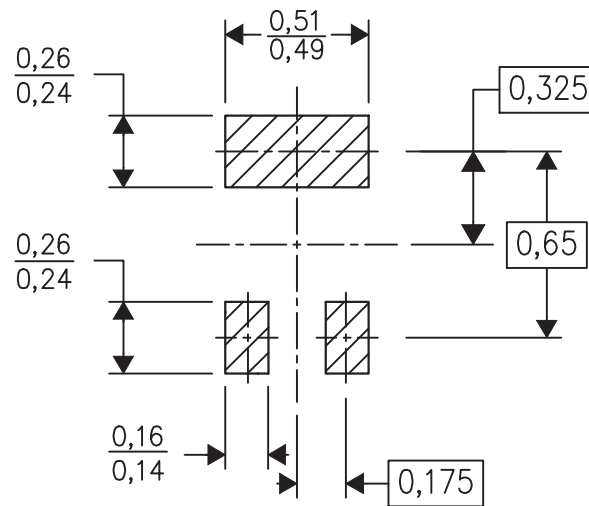
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

### 7.1 Mechanical Dimensions



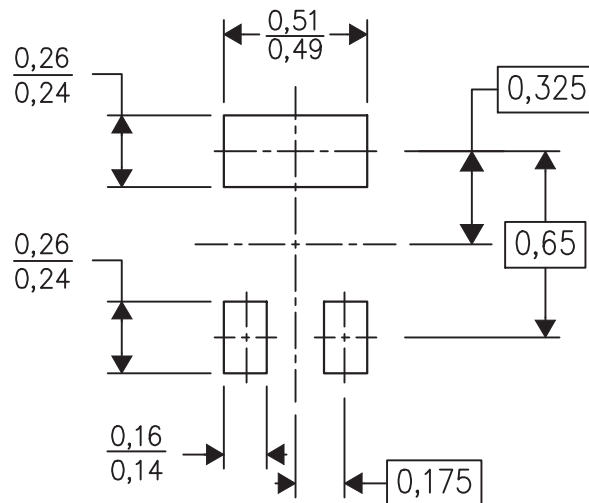


## 7.2 Recommended Minimum PCB Layout



(1) All dimensions are in millimeters.

## 7.3 Recommended Stencil Pattern



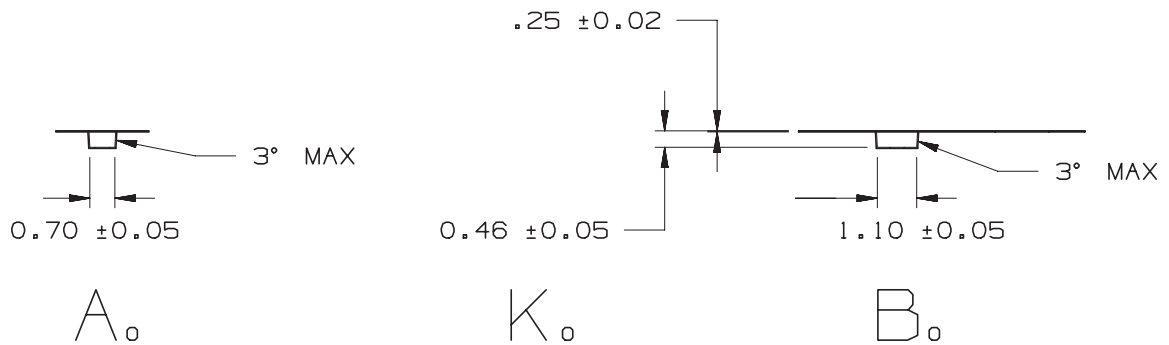
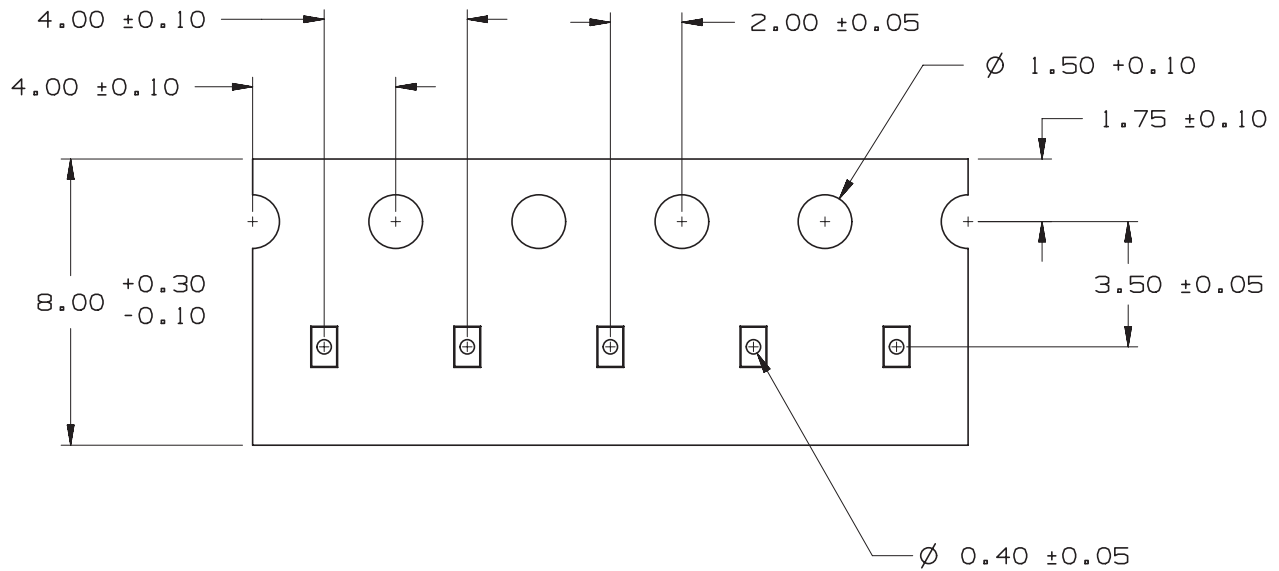
(1) All dimensions are in millimeters.

**CSD23382F4**

SLPS453C – MAY 2014 – REVISED OCTOBER 2014

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**7.4 CSD23382F4 Embossed Carrier Tape Dimensions**



- (1) Pin 1 is oriented in the top-right quadrant of the tape enclosure (quadrant 2), closest to the carrier tape sprocket holes.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD23382F4	ACTIVE	PICOSTAR	YJC	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	0 to 0	EM	<a href="#">Samples</a>
CSD23382F4T	ACTIVE	PICOSTAR	YJC	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	0 to 0	EM	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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